



CMOS Static RAM 64K (8K x 8-Bit)

IDT7164S
IDT7164L

Features

- ♦ **High-speed address/chip select access time**
 - Military: 20/25/35/45/55/70/85/100ns (max.)
 - Industrial: 20/25ns (max.)
 - Commercial: 20/25ns (max.)
- ♦ **Low power consumption**
- ♦ **Battery backup operation – 2V data retention voltage (L Version only)**
- ♦ **Produced with advanced CMOS high-performance technology**
- ♦ **Inputs and outputs directly TTL-compatible**
- ♦ **Three-state outputs**
- ♦ **Available in 28-pin DIP, Cerdip and SOJ**
- ♦ **Military product compliant to MIL-STD-883, Class B**
- ♦ **Green parts available, see ordering information**

Description

The IDT7164 is a 65,536 bit high-speed static RAM organized as 8K x 8. It is fabricated using high-performance, high-reliability CMOS technology.

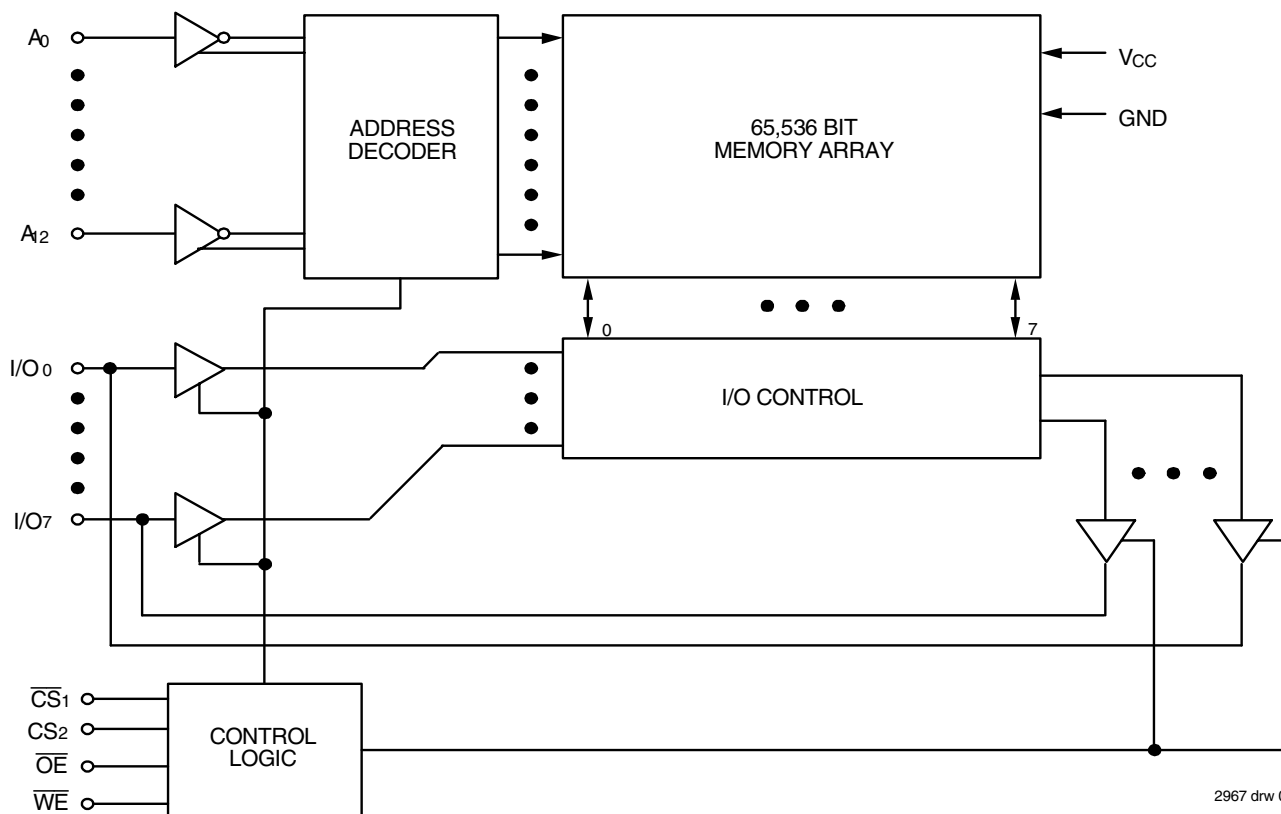
Address access times as fast as 20ns are available and the circuit offers a reduced power standby mode. When CS₁ goes HIGH or CS₂ goes LOW, the circuit will automatically go to, and remain in, a low-power standby mode. The low-power (L) version also offers a battery backup data retention capability at power supply levels as low as 2V.

All inputs and outputs of the IDT7164 are TTL-compatible and operation is from a single 5V supply, simplifying system designs. Fully static asynchronous circuitry is used, requiring no clocks or refreshing for operation.

The IDT7164 is packaged in a 28-pin 300 mil Cerdip, a 28-pin 600 mil Cerdip, 300mil Plastic DIP and 300mil SOJ

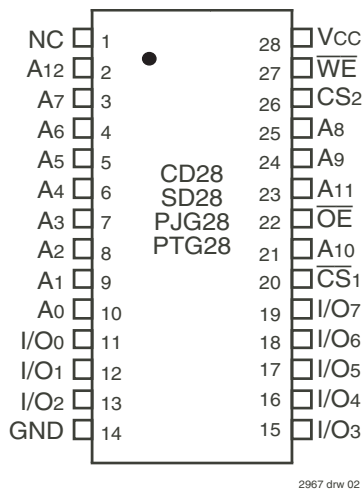
Military grade product is manufactured in compliance with MIL-STD-883, Class B, making it ideally suited to military temperature applications demanding the highest level of performance and reliability.

Functional Block Diagram



DECEMBER 2016

Pin Configurations



**DIP/SOJ
Top View**

Absolute Maximum Ratings⁽¹⁾

Symbol	Rating	Com'l.	Mil.	Unit
$V_{TERM}^{(2)}$	Terminal Voltage with Respect to GND	-0.5 to +7.0	-0.5 to +7.0	V
T_A	Operating Temperature	0 to +70	-55 to +125	°C
T_{BIAS}	Temperature Under Bias	-55 to +125	-65 to +135	°C
T_{STG}	Storage Temperature	-55 to +125	-65 to +150	°C
P_T	Power Dissipation	1.0	1.0	W
I_{OUT}	DC Output Current	50	50	mA

2967 tbl 02

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{TERM} must not exceed $V_{CC} + 0.5V$.

Pin Descriptions

Name	Description
$A_0 - A_{12}$	Address
$I/O_0 - I/O_7$	Data Input/Output
$\overline{CS}_1$	Chip Select
CS_2	Chip Select
$\overline{WE}$	Write Enable
$\overline{OE}$	Output Enable
GND	Ground
V_{CC}	Power

2967 tbl 01

Truth Table^(1,2,3)

$\overline{WE}$	$\overline{CS}_1$	CS_2	$\overline{OE}$	I/O	Function
X	H	X	X	High-Z	Deselected - Standby (LSB)
X	X	L	X	High-Z	Deselected - Standby (LSB)
X	V_{HC}	V_{HC} or V_{LC}	X	High-Z	Deselected - Standby (LSB1)
X	X	V_{LC}	X	High-Z	Deselected - Standby (LSB1)
H	L	H	H	High-Z	Output Disabled
H	L	H	L	$DATA_{OUT}$	Read Data
L	L	H	X	$DATA_{IN}$	Write Data

2967 tbl 03

NOTES:

- CS_2 will power-down $\overline{CS}_1$, but $\overline{CS}_1$ will not power-down CS_2 .
- H = V_{IH} , L = V_{IL} , X = don't care.
- $V_{LC} = 0.2V$, $V_{HC} = V_{CC} - 0.2V$

Recommended DC Operating Conditions

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{CC}	Supply Voltage	4.5	5.0	5.5	V
GND	Ground	0	0	0	V
V_{IH}	Input HIGH Voltage	2.2	—	$V_{CC} + 0.5$	V
V_{IL}	Input LOW Voltage	-0.5 ⁽¹⁾	—	0.8	V

2967 tbl 05

NOTE:

- V_{IL} (min.) = -1.5V for pulse width less than 10ns, once per cycle.

Recommended Operating Temperature and Supply Voltage

Grade	Temperature	GND	V_{CC}
Military	-55°C to +125°C	0V	5V ± 10%
Industrial	-40°C to +85°C	0V	5V ± 10%
Commercial	0°C to +70°C	0V	5V ± 10%

2967 tbl 04

Capacitance (TA = +25°C, f = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	8	pF
C _{IO}	I/O Capacitance	V _{OUT} = 0V	8	pF

2967 tbl 06

NOTE:

1. This parameter is determined by device characterization, but is not production tested.

DC Electrical Characteristics⁽¹⁾ (V_{CC} = 5.0V ± 10%, V_{LC} = 0.2V, V_{HC} = V_{CC} - 0.2V)

Symbol	Parameter	Power	7164S20 7164L20			7164S25 7164L25			Unit
			Com'l.	Ind.	Mil.	Com'l.	Ind.	Mil.	
ICC1	Operating Power Supply Current CS ₁ = V _{IL} , CS ₂ = V _{IH} , Outputs Open V _{CC} = Max., f = 0 ⁽²⁾	S	100	110	110	90	110	110	mA
		L	90	100	100	90	100	100	
ICC2	Dynamic Operating Current CS ₁ = V _{IL} , CS ₂ = V _{IH} , Outputs Open V _{CC} = Max., f = f _{MAX} ⁽²⁾	S	170	170	180	170	170	180	mA
		L	150	150	160	150	150	160	
ISB	Standby Power Supply Current (TTL Level), CS ₁ ≥ V _{IH} , CS ₂ ≤ V _{IL} , Outputs Open, V _{CC} = Max., f = f _{MAX} ⁽²⁾	S	20	20	20	20	20	20	mA
		L	3	3	5	3	3	5	
ISB1	Full Standby Power Supply Current (CMOS Level), f = 0 ⁽²⁾ , V _{CC} = Max. 1. CS ₁ ≥ V _{HC} and CS ₂ ≥ V _{HC} , or 2. CS ₂ ≤ V _{LC}	S	15	15	20	15	15	20	mA
		L	0.2	0.2	1	0.2	0.2	1	

2967 tbl 07

Symbol	Parameter	Power	7164S35 7164L35	7164S45 7164L45	7164S55 7164L55	7164S70 7164L70	7164S85/100 7164L85/100	Unit
			Mil.	Mil.	Mil.	Mil.	Mil.	
ICC1	Operating Power Supply Current CS ₁ = V _{IL} , CS ₂ = V _{IH} , Outputs Open V _{CC} = Max., f = 0 ⁽²⁾	S	100	100	100	100	100	mA
		L	90	90	90	90	90	
ICC2	Dynamic Operating Current CS ₁ = V _{IL} , CS ₂ = V _{IH} , Outputs Open V _{CC} = Max., f = f _{MAX} ⁽²⁾	S	160	160	160	160	160	mA
		L	140	130	125	120	120	
ISB	Standby Power Supply Current (TTL Level), CS ₁ ≥ V _{IH} , CS ₂ ≤ V _{IL} , Outputs Open, V _{CC} = Max., f = f _{MAX} ⁽²⁾	S	20	20	20	20	20	mA
		L	5	5	5	5	5	
ISB1	Full Standby Power Supply Current (CMOS Level), f = 0 ⁽²⁾ , V _{CC} = Max. 1. CS ₁ ≥ V _{HC} and CS ₂ ≥ V _{HC} , or 2. CS ₂ ≤ V _{LC}	S	20	20	20	20	20	mA
		L	1	1	1	1	1	

2967 tbl 08

NOTES:

1. All values are maximum guaranteed values.
2. f_{MAX} = 1/TRC (all address inputs are cycling at f_{MAX}); f = 0 means no address input lines are changing.

DC Electrical Characteristics ($V_{CC} = 5.0V \pm 10\%$)

Symbol	Parameter	Test Conditions	IDT7164S		IDT7164L		Unit
			Min.	Max.	Min.	Max.	
$ I_{LI} $	Input Leakage Current	$V_{CC} = \text{Max.}, V_{IN} = \text{GND to } V_{CC}$ MIL. COM'L. & IND	—	10 5	—	5 2	μA
$ I_{LO} $	Output Leakage Current	$V_{CC} = \text{Max.}, \overline{CS}_1 = V_{IH}, V_{OUT} = \text{GND to } V_{CC}$ MIL. COM'L. & IND	—	10 5	—	5 2	μA
V_{OL}	Output Low Voltage	$I_{OL} = 8\text{mA}, V_{CC} = \text{Min.}$	—	0.4	—	0.4	V
		$I_{OL} = 10\text{mA}, V_{CC} = \text{Min.}$	—	0.5	—	0.5	
V_{OH}	Output High Voltage	$I_{OH} = -4\text{mA}, V_{CC} = \text{Min.}$	2.4	—	2.4	—	V

2967 tbl 09

Data Retention Characteristics Over All Temperature Ranges (L Version Only) ($V_{LC} = 0.2V, V_{HC} = V_{CC} - 0.2V$)

Symbol	Parameter	Test Condition	Min.	Typ. ⁽¹⁾ $V_{CC} @$		Max. $V_{CC} @$		Unit
				2.0V	3.0V	2.0V	3.0V	
VDR	V_{CC} for Data Retention	—	2.0	—	—	—	—	V
I_{CCDR}	Data Retention Current	MIL. COM'L. & IND	— —	10 10	15 15	200 60	300 90	μA
$t_{CDR}^{(3)}$	Chip Deselect to Data Retention Time	1. $\overline{CS}_1 \geq V_{HC}$ $CS_2 \geq V_{HC}$, or 2. $CS_2 \leq V_{LC}$	0	—	—	—	—	ns
$t_R^{(3)}$	Operation Recovery Time		$t_{RC}^{(2)}$	—	—	—	—	ns
$ I_{LI} ^{(3)}$	Input Leakage Current		—	—	—	2	2	μA

2967 tbl 10

NOTES:

1. $T_A = +25^\circ\text{C}$.
2. t_{RC} = Read Cycle Time.
3. This parameter is guaranteed by device characterization, but is not production tested.

AC Test Conditions

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	5ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
AC Test Load	See Figures 1 and 2

2967 tbl 11

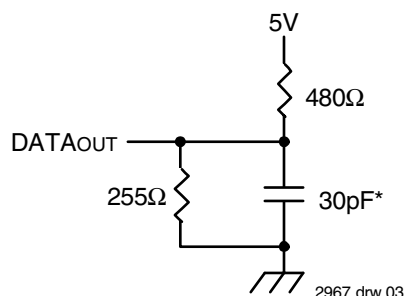


Figure 1. AC Test Load

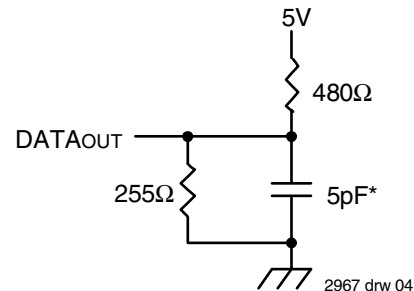


Figure 2. AC Test Load

(for $t_{CLZ1}, t_{CLZ2}, t_{OLZ}, t_{CHZ1}, t_{CHZ2}, t_{OHZ}, t_{OW},$ and t_{WHZ})

*Includes scope and jig capacitances

AC Electrical Characteristics (Vcc = 5.0V ± 10%, All Temperature Ranges)

Symbol	Parameter	7164S20 7164L20		7164S25 7164L25		Unit
		Min.	Max.	Min.	Max.	
Read Cycle						
t _{RC}	Read Cycle Time	20	—	25	—	ns
t _{AA}	Address Access Time	—	19	—	25	ns
t _{ACS1} ⁽¹⁾	Chip Select-1 Access Time	—	20	—	25	ns
t _{ACS2} ⁽¹⁾	Chip Select-2 Access Time	—	25	—	30	ns
t _{CLZ1,2} ⁽²⁾	Chip Select-1, 2 to Output in Low-Z	5	—	5	—	ns
t _{OE}	Output Enable to Output Valid	—	8	—	12	ns
t _{OLZ} ⁽²⁾	Output Enable to Output in Low-Z	0	—	0	—	ns
t _{CHZ1,2} ⁽²⁾	Chip Select-1,2 to Output in High-Z	—	9	—	13	ns
t _{OHZ} ⁽²⁾	Output Disable to Output in High-Z	—	8	—	10	ns
t _{OH}	Output Hold from Address Change	5	—	5	—	ns
t _{PU} ⁽²⁾	Chip Select to Power Up Time	0	—	0	—	ns
t _{PD} ⁽²⁾	Chip Deselect to Power Down Time	—	20	—	25	ns
Write Cycle						
t _{WC}	Write Cycle Time	20	—	25	—	ns
t _{CW1,2}	Chip Select to End-of-Write	15	—	18	—	ns
t _{AW}	Address Valid to End-of-Write	15	—	18	—	ns
t _{AS}	Address Set-up Time	0	—	0	—	ns
t _{WP}	Write Pulse Width	15	—	21	—	ns
t _{WR1}	Write Recovery Time ($\overline{CS_1}$, $\overline{WE}$)	0	—	0	—	ns
t _{WR2}	Write Recovery Time (CS ₂)	5	—	5	—	ns
t _{WHZ} ⁽²⁾	Write Enable to Output in High-Z	—	8	—	10	ns
t _{DW}	Data to Write Time Overlap	10	—	13	—	ns
t _{DH1}	Data Hold from Write Time ($\overline{CS_1}$, $\overline{WE}$)	0	—	0	—	ns
t _{DH2}	Data Hold from Write Time (CS ₂)	5	—	5	—	ns
t _{OW} ⁽²⁾	Output Active from End-of-Write	4	—	4	—	ns

2967 tbl 12

NOTES:

- Both chip selects must be active for the device to be selected.
- This parameter is guaranteed by device characterization, but is not production tested.

AC Electrical Characteristics (con't.) (V_{cc} = 5.0V ± 10%, Military Temperature Ranges)

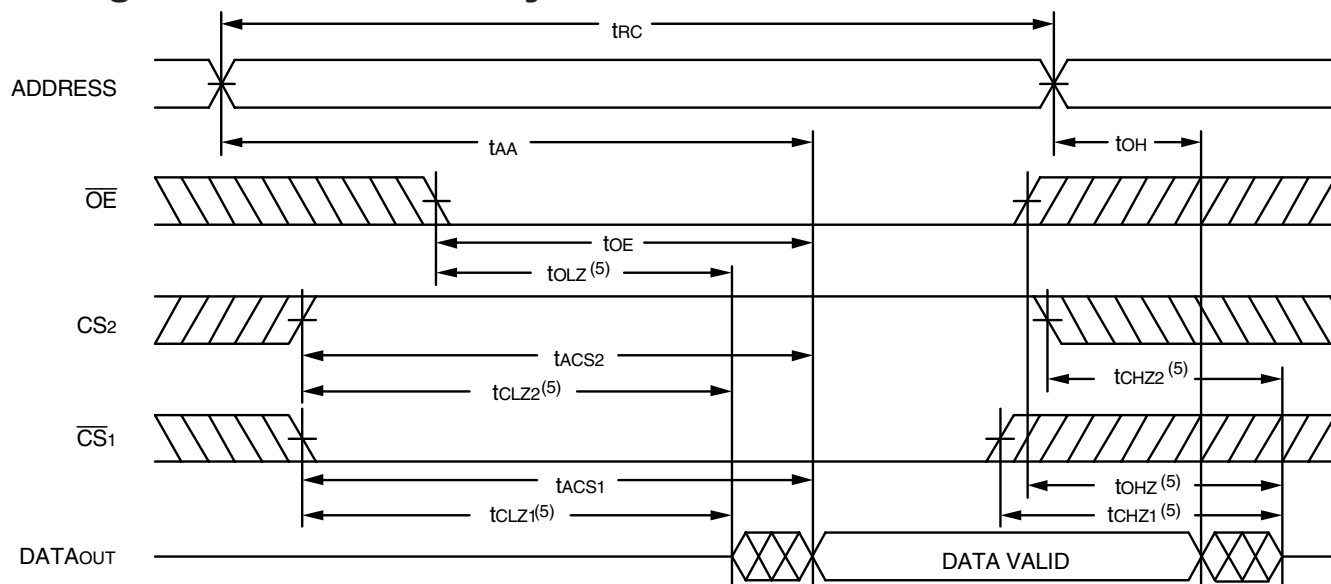
Symbol	Parameter	7164S35 7164L35		7164S45 7164L45		7164S55 7164L55		7164S70 7164L70		7164S85/100 7164L85/100		Unit
		Max.	Min.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Read Cycle												
t _{RC}	Read Cycle Time	35	—	45	—	55	—	70	—	85/100	—	ns
t _{AA}	Address Access Time	—	35	—	45	—	55	—	70	—	85/100	ns
t _{ACS1} ⁽¹⁾	Chip Select-1 Access Time	—	35	—	45	—	55	—	70	—	85/100	ns
t _{ACS2} ⁽¹⁾	Chip Select-2 Access Time	—	40	—	45	—	55	—	70	—	85/100	ns
t _{CLZ1,2} ⁽²⁾	Chip Select-1, 2 to Output in Low-Z	5	—	5	—	5	—	5	—	5	—	ns
t _{OE}	Output Enable to Output Valid	—	18	—	25	—	30	—	35	—	40	ns
t _{OLZ} ⁽²⁾	Output Enable to Output in Low-Z	0	—	0	—	0	—	0	—	0	—	ns
t _{CHZ1,2} ⁽²⁾	Chip Select-1,2 to Output in High-Z	—	15	—	20	—	25	—	30	—	35	ns
t _{OHZ} ⁽²⁾	Output Disable to Output in High-Z	—	15	—	20	—	25	—	30	—	35	ns
t _{OH}	Output Hold from Address Change	5	—	5	—	5	—	5	—	5	—	ns
t _{PU} ⁽²⁾	Chip Select to Power Up Time	0	—	0	—	0	—	0	—	0	—	ns
t _{PD} ⁽²⁾	Chip Deselect to Power Down Time	—	35	—	45	—	55	—	70	—	85/100	ns
Write Cycle												
t _{WC}	Write Cycle Time	35	—	45	—	55	—	70	—	85/100	—	ns
t _{CW1,2}	Chip Select to End-of-Write	25	—	33	—	50	—	60	—	75	—	ns
t _{AW}	Address Valid to End-of-Write	25	—	33	—	50	—	60	—	75	—	ns
t _{AS}	Address Set-up Time	0	—	0	—	0	—	0	—	0	—	ns
t _{WP}	Write Pulse Width	25	—	25	—	50	—	60	—	75	—	ns
t _{WR1}	Write Recovery Time ($\overline{CS_1}$, $\overline{WE}$)	0	—	0	—	0	—	0	—	0	—	ns
t _{WR2}	Write Recovery Time (CS ₂)	5	—	5	—	5	—	5	—	5	—	ns
t _{WHZ} ⁽²⁾	Write Enable to Output in High-Z	—	14	—	18	—	25	—	30	—	35	ns
t _{DW}	Data to Write Time Overlap	15	—	20	—	25	—	30	—	35	—	ns
t _{DH1}	Data Hold from Write Time ($\overline{CS_1}$, $\overline{WE}$)	0	—	0	—	0	—	0	—	0	—	ns
t _{DH2}	Data Hold from Write Time (CS ₂)	5	—	5	—	5	—	5	—	5	—	ns
t _{OW} ⁽²⁾	Output Active from End-of-Write	4	—	4	—	4	—	4	—	4	—	ns

2967 tbl 13

NOTES:

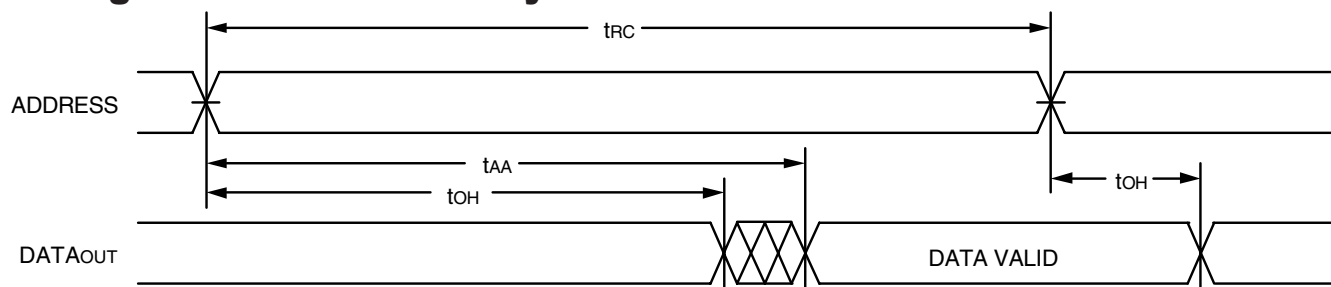
- Both chip selects must be active for the device to be selected.
- This parameter is guaranteed by device characterization, but is not production tested.

Timing Waveform of Read Cycle No. 1⁽¹⁾



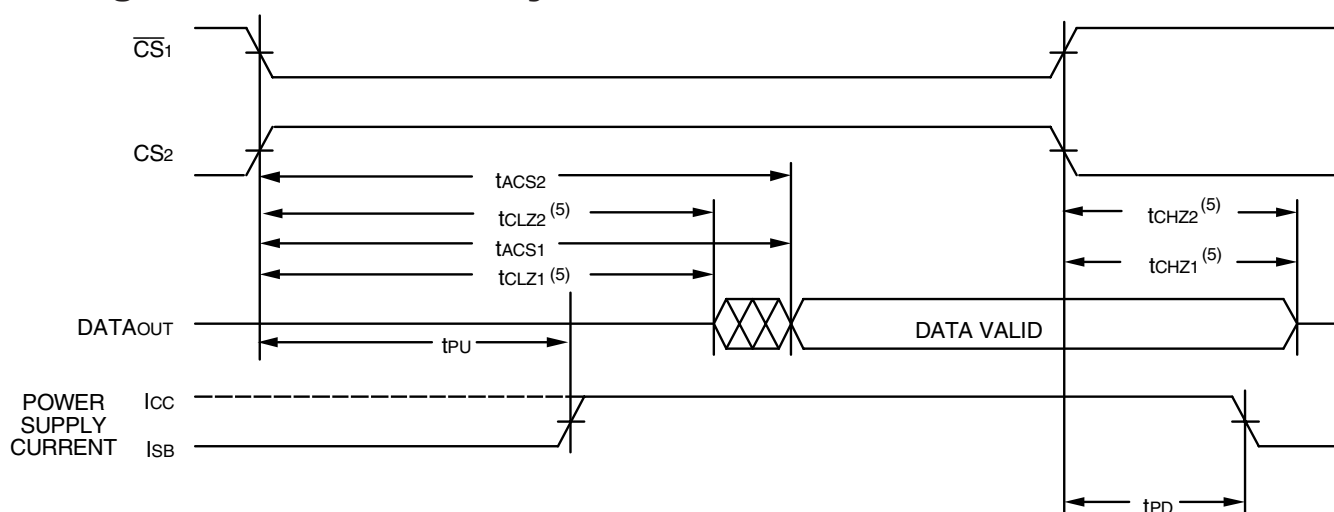
2967 drw 05

Timing Waveform of Read Cycle No. 2^(1,2,4)



2967 drw 06

Timing Waveform of Read Cycle No. 3^(1,3,4)

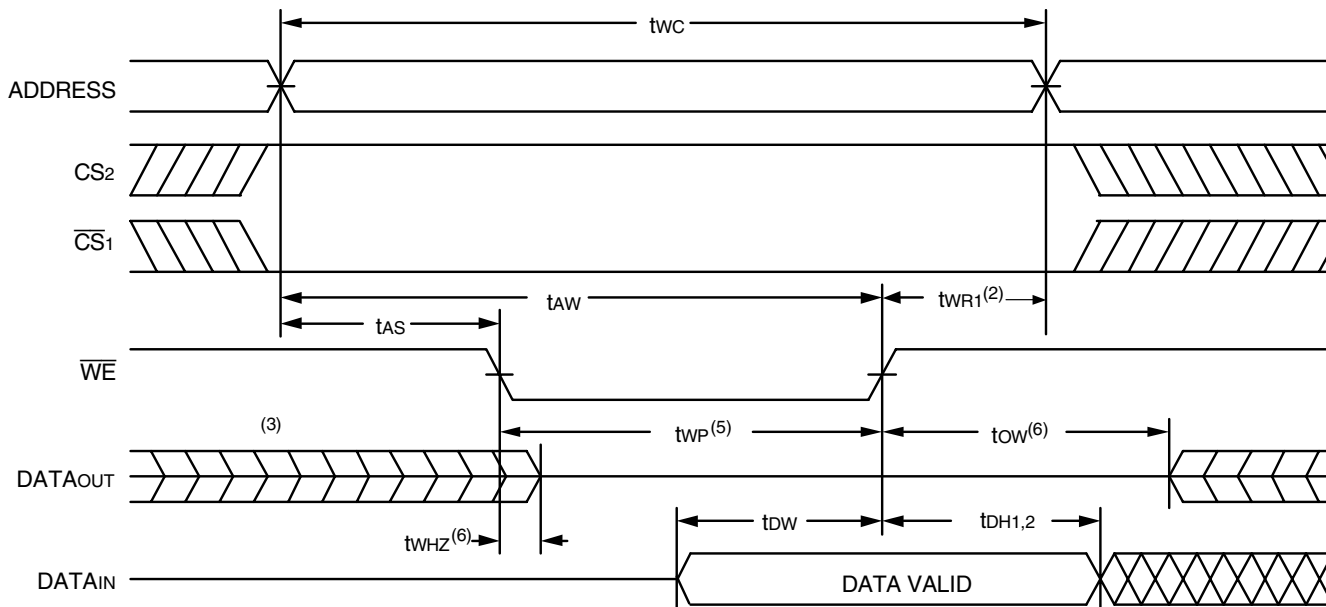


NOTES:

1. $\overline{WE}$ is HIGH for Read cycle.
2. Device is continuously selected, $\overline{CS1}$ is LOW, $CS2$ is HIGH.
3. Address valid prior to or coincident with $\overline{CS1}$ transition LOW and $CS2$ transition HIGH.
4. $\overline{OE}$ is LOW.
5. Transition is measured $\pm 200\text{mV}$ from steady state.

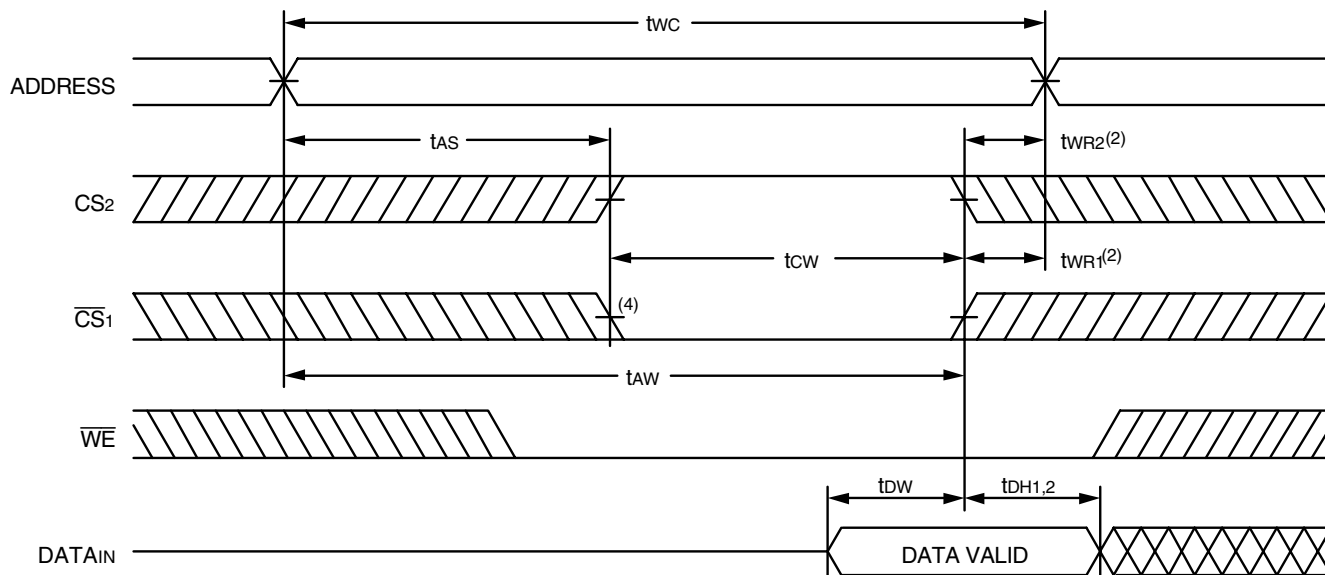
2967 drw 07

Timing Waveform of Write Cycle No. 1 ($\overline{WE}$ Controlled Timing)^(1,5)



2967 drw 08

Timing Waveform of Write Cycle No. 2 ($\overline{CS}$ Controlled Timing)⁽¹⁾

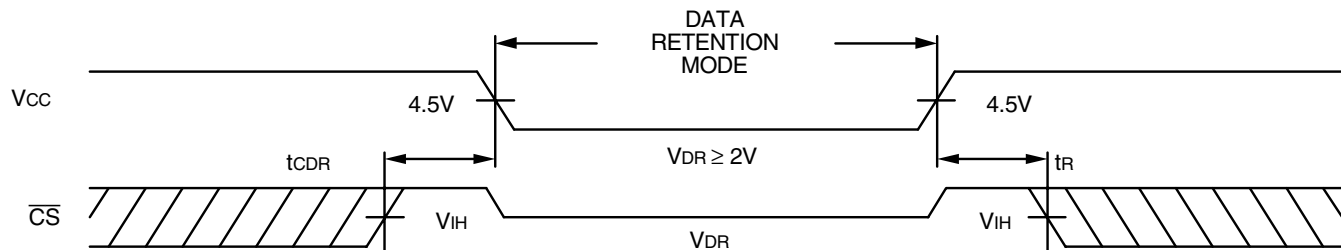


2967 drw 09

NOTES:

1. A write occurs during the overlap of a LOW $\overline{WE}$, a LOW $\overline{CS1}$ and a HIGH $CS2$.
2. $tWR1,2$ is measured from the earlier of $\overline{CS1}$ or $\overline{WE}$ going HIGH or $CS2$ going LOW to the end of the write cycle.
3. During this period, I/O pins are in the output state so that the input signals must not be applied.
4. If the $\overline{CS1}$ LOW transition or $CS2$ HIGH transition occurs simultaneously with or after the $\overline{WE}$ LOW transition, the outputs remain in a high-impedance state.
5. $\overline{OE}$ is continuously HIGH. If $\overline{OE}$ is LOW during a $\overline{WE}$ controlled write cycle, the write pulse width must be the larger of tWP or $(tWHZ + tDW)$ to allow the I/O drivers to turn off and data to be placed on the bus for the required tDW . If $\overline{OE}$ is HIGH during a $\overline{WE}$ controlled write cycle, this requirement does not apply and the minimum write pulse width is as short as the specified tWP .
6. Transition is measured $\pm 200mV$ from steady state.

Low Vcc Data Retention Waveform



2967 drw 10

Ordering Information

7164	X	XX	XXX	X	X	X		
Device Type	Power	Speed	Package		Process/ Temperature Range			
							Blank 8	Tube Tape and Reel
							Blank I ⁽¹⁾ B	Commercial (0°C to +70°C) Industrial (-40°C to +85°C) Military (-55°C to +125°C) Compliant with MIL-STD-883, Class B
							G ⁽²⁾	Green
							Y	300 mil SOJ (PJG28)
							TP	300 mil Plastic DIP (PTG28)
							D	600 mil CERDIP (CD28)
							TD	300 mil CERDIP (SD28)
							20	Commercial, Industrial & Military
							25	Commercial, Industrial & Military
							35	Military Only
							45	Military Only
							55	Military Only
							70	Military Only
							85	Military Only
							100	Military Only
							S	Standard Power
							L	Low Power

Speed in nanoseconds

NOTES:

- Contact your local sales office for industrial temp range for other speeds, packages and powers.
- Green parts available. For specific speeds, packages and powers contact your local sales office.

2967 drw 11

Datasheet Document History

01/13/00		Updated to new format
	Pp. 1, 2, 3, 5, 10	Added Industrial Temperature range offerings
	Pp. 1, 3, 9	Removed commercial 70ns speed grade offering
	Pp. 1, 3, 6, 10	Added 100ns speed grade specification details
	Pg. 3	Revised notes and footnotes in DC Electrical tables
	Pp. 5, 6	Revised notes and footnotes in AC Electrical tables
	Pg. 8	Removed Note 1 from Write Cycle No. 1 and No. 2 diagrams; renumbered notes and footnotes
	Pp. 9, 10	Separated Ordering Information into commercial, industrial, and military offerings
	Pg. 11	Added Datasheet Document History
08/09/00		Not recommended for new designs
02/01/01		Removed "Not recommended for new designs"
12/07/01	Pg. 10	Add PJ28 to Industrial temperature.
09/30/04	Pg. 9, 10	Added "restricted hazardous substance device" to ordering information.
11/16/06	Pg. 3	Added industrial temp power limits for 20ns part. Changed power limits for 25ns part for commercial and industrial. Changed power limits for commercial and industrial for 35ns part.
	Pg. 10	Added 20ns part to ordering information. Refer to PCN SR-0602-01
02/20/07	Pg. 9, 10	Added L generation die step to data sheet ordering information.
04/27/11	Pg. 1-3,5,6,9	Obsoleted 24-pin 600 mil, 15ns for Commercial and 35ns for Industrial & Commercial.
		Added Tape and Reel to Ordering information and updated description of Restricted hazardous substance device to Green.
10/30/13	Pg. 1	In the Description: Removed reference to IDT's fabrication and removed "the latest revision of".
12/06/16	Pg. 2	Removed half moon from the pin configuration diagram for all packages to reflect pin 1 orientation and added dot at pin 1
		Updated the package codes in the DIP/SOJ pin configuration
	Pg. 9	Updated the package codes in the Ordering Information
		Updated the BLANK designator from "Tube and Tray" to "Tube" in Ordering Information
	Pg. 1 & 9	Added standard footnotes to Ordering Information with instructions for ordering Industrial temp and Green parts



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[5962-3829410MXA](#) [5962-3829410MZA](#) [7164S35DB](#) [7164L25YG8](#) [5962-3829407MXA](#) [5962-3829407MZA](#)
[7164L20YGI](#) [5962-3829409MXA](#) [5962-3829409MZA](#) [5962-3829415MZA](#) [5962-3829415MXA](#) [7164L20TDB](#)
[7164S85DB](#) [7164S20YG](#) [7164L55DB](#) [7164S20DB](#) [7164L20YGI8](#) [5962-3829417MXA](#) [5962-3829417MZA](#)
[7164S25DB](#) [7164S25YG](#) [7164S25YGI8](#) [7164S20TPG](#) [7164S20TDB](#) [7164S20YGI](#) [5962-3829413MXA](#)
[7164L100DB](#) [5962-3829413MZA](#) [7164S25YG8](#) [7164L35TDB](#) [7164L20DB](#) [7164L20YG](#) [7164L20YG8](#) [7164L25DB](#)
[7164L25YG](#) [5962-3829406MXA](#) [7164L25YGI8](#) [7164S45DB](#) [5962-3829411MZA](#) [5962-3829411MXA](#) [7164L85TDB](#)
[5962-8552512XA](#) [7164S70TDB](#) [7164L35DB](#) [7164S20YGI8](#)

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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